

**CYPD1120** 

# USB Power Delivery Alternate Mode Controller on Type-C

# **General Description**

The CYPD1120 device belongs to Cypress's CCG1 product family, which provides a complete USB Type-C and USB Power Delivery port control solution. The scalable and reconfigurable core architecture of CCG1 enables a base Type-C solution that can scale to a complete 100-W USB Power Delivery with Alternate Mode mux support. CCG1 is also a Type-C cable ID IC for active and passive cables. The ARM<sup>®</sup> Cortex<sup>®</sup>-M0 CPU based core can use common open source firmware or custom solutions developed with common libraries and APIs. CCG1 is the CC controller that detects connector insert, plug orientation, and V<sub>CONN</sub> switching signals. CCG1 makes it easier to add USB Power Delivery to any architecture because it provides the control signals to manage external VBUS and V<sub>CONN</sub> power management solutions as well as external mux controls for most single cable-docking solutions. CCG1's packaging options, and programmability, enables any USB Type-C and USB Power Delivery solution.

# Applications

- Dongles, docking stations
- Type-C to DisplayPort
- Type-C to HDMI
- Type-C to DVI
- Type-C to VGA

# Features

# 32-bit MCU Subsystem

48-MHz ARM Cortex-M0 CPU with 32-KB flash and 4-KB SRAM

# Integrated Analog Blocks

■ 12-bit, 1-Msps ADC for VBUS voltage and current monitoring

# **Integrated Digital Blocks**

- Two configurable 16-bit TCPWM blocks
- One I<sup>2</sup>C master or slave

#### **Type-C Support**

Integrated transceiver (BB PHY)

### **PD Support**

Supports VESA DisplayPort Alternate Mode on USB Type-C Standard Version 1.0

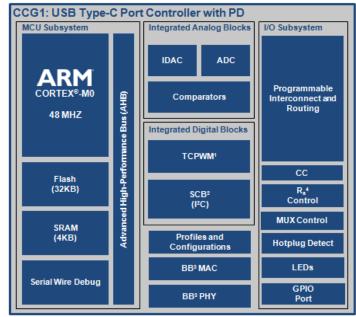
### Low-power Operation

- 1.8-V to 5.5-V operation
  - Sleep 1.3 mA, Deep Sleep 1.3 uA<sup>[2]</sup>

### Packages

- 40-pin QFN
- 35-ball wafer-level CSP (WLCSP)

# Figure 1. CCG1 Block Diagram<sup>[2, 3, 4, 5]</sup>



#### Notes

- 1. Values measured for CCG1 silicon only. Application specific power numbers may be higher.
- 2. Timer, counter, pulse-width modulation block.
- Serial communication block configurable as I<sup>2</sup>C.
   Base band
- 4. Base band.
- 5. Termination resistor denoting an Alternate Mode Adaptor.

**Cypress Semiconductor Corporation** Document Number: 001-96786 Rev. \*C 198 Champion Court

San Jose, CA 95134-1709 • 408-943-2600 Revised April 21, 2017



# Contents

Functional Definition	3
CPU and Memory Subsystem	
System Resources	
GPIO	
Pin Definitions	
Pinouts	6
Power	
Electrical Specifications	9
Absolute Maximum Ratings	
Device Level Specifications	
Digital Peripherals	
Memory	
System Resources	
Applications in Detail	

Ordering Information	. 18
Ordering Code Definitions	. 18
Packaging	. 19
Acronyms	. 21
Document Conventions	. 22
Units of Measure	. 22
Revision History	. 23
Sales, Solutions, and Legal Information	. 24
Worldwide Sales and Design Support	. 24
Products	. 24
PSoC Solutions	.24
Cypress Developer Community	. 24
Technical Support	



# **Functional Definition**

#### **CPU and Memory Subsystem**

#### CPU

The Cortex-M0 CPU in the CCG1 is part of the 32-bit MCU subsystem, which is optimized for low-power operation with extensive clock gating. It mostly uses 16-bit instructions and executes a subset of the Thumb-2 instruction set. This enables fully compatible binary upward migration of the code to higher performance processors such as the Cortex-M3 and M4, thus enabling upward compatibility. The Cypress implementation includes a hardware multiplier that provides a 32-bit result in one cycle. It includes a nested vectored interrupt controller (NVIC) block with 32 interrupt inputs and a Wakeup Interrupt Controller (WIC). The WIC can wake the processor up from the Deep Sleep mode, allowing power to be switched off to the main processor when the chip is in the Deep Sleep mode. The Cortex-M0 CPU provides a Non-Maskable Interrupt (NMI) input, which is made available to the user when it is not in use for system functions requested by the user.

The CPU also includes a debug interface, the serial wire debug (SWD) interface, which is a 2-wire form of JTAG; the debug configuration used for CCG1 has four break-point (address) comparators and two watchpoint (data) comparators.

#### Flash

The CCG1 device has a flash module with a flash accelerator, tightly coupled to the CPU to improve average access times from the flash block. The flash block is designed to deliver 1 wait-state (WS) access time at 48 MHz and 0-WS access time at 24 MHz. The flash accelerator delivers 85% of single-cycle SRAM access performance on average. Part of the flash module can be used to emulate EEPROM operation if required.

#### SROM

A supervisory ROM that contains boot and configuration routines is provided.

#### System Resources

#### Power System

The power system is described in detail in the section Power on page 7. It provides assurance that voltage levels are as required for each respective mode and either delay mode entry (on power-on reset (POR), for example) until voltage levels are as required for proper function or generate resets (Brown-Out Detect (BOD)) or interrupts (Low Voltage Detect (LVD)). The CCG1 operates with a single external supply over the range of 1.8 to 5.5 V and has three different power modes: Active, Sleep, and Deep Sleep; transitions between modes are managed by the power system.

#### Serial Communication Blocks (SCB)

The CCG1 has one SCB, which can implement an  $I^2C$  interface. The hardware  $I^2C$  block implements a full multi-master and slave interface (it is capable of multimaster arbitration). In addition, the block supports an 8-deep FIFO for receive and transmit which, by increasing the time given for the CPU to read data, greatly reduces the need for clock stretching caused by the CPU not having read data on time. The  $I^2C$  peripheral is compatible with the  $I^2C$  Standard-mode, Fast-mode, and Fast-mode Plus devices, as defined in the NXP  $I^2C$ -bus specification and user manual (UM10204). The  $I^2C$  bus I/O is implemented with GPIO in open-drain modes.

The CCG1 is not completely compliant with the I<sup>2</sup>C spec in the following respects:

- GPIO cells are not overvoltage tolerant and, therefore, cannot be hot-swapped or powered up independently of the rest of the I<sup>2</sup>C system.
- Fast-mode Plus has an I<sub>OL</sub> specification of 20 mA at a V<sub>OL</sub> of 0.4 V. The GPIO cells can sink a maximum of 8 mA I<sub>OL</sub> with a V<sub>OL</sub> maximum of 0.6 V.
- Fast-mode and Fast-mode Plus specify minimum Fall times, which are not met with the GPIO cell; Slow strong mode can help meet this spec depending on the Bus Load.
- When the SCB is an I<sup>2</sup>C Master, it interposes an IDLE state between NACK and Repeated Start; the I<sup>2</sup>C spec defines Bus free as following a Stop condition so other Active Masters do not intervene but a Master that has just become activated may start an Arbitration cycle.
- When the SCB is in the I<sup>2</sup>C Slave mode, and Address Match on External Clock is enabled (EC\_AM = 1) along with operation in the internally clocked mode (EC\_OP = 0), then its I<sup>2</sup>C address must be even.

#### GPIO

The CCG1 has up to 10 GPIOs, which are configured for various functions. Refer to the pinout tables for the definitions. The GPIO block implements the following:

- Eight drive strength modes:
- □ Analog input mode (input and output buffers disabled)
- Input only
- Weak pull-up with strong pull-down
- □ Strong pull-up with weak pull-down
- Open drain with strong pull-down
- Open drain with strong pull-up
- □ Strong pull-up with strong pull-down
- Weak pull-up with weak pull-down
- Input threshold select (CMOS or LVTTL).
- Individual control of input and output buffer enabling/disabling in addition to the drive strength modes.
- Hold mode for latching previous state (used for retaining I/O state in Deep Sleep mode).
- Selectable slew rates for dV/dt related noise control to improve EMI.

During power-on and reset, the I/O pins are forced to the disable state so as not to crowbar any inputs and/or cause excess turn-on current. A multiplexing network, known as a high-speed I/O matrix, is used to multiplex between various signals that may connect to an I/O pin.



# **Pin Definitions**

Table 1 provides the pin definitions for 40-pin QFN and 35-ball WLCSP for the notebook, tablet, smartphone, and monitor applications. Refer to Table 20 on page 18 for par numbers to package mapping.

Table 1.	Pin Definition	for 40-Pin QFN and	35-Ball WLCSP
----------	----------------	--------------------	---------------

Functional Pin Name	CYPD1120-35FNXIT	CYPD1120-40LQXI	Туре	Description
CC1_RX	C4	35	I	CC1 control 0: TX enabled z: RX sense
CC1_TX	D7	38	0	Configuration Channel 1
SWD_IO	D1	12	I/O	SWD IO
SWD_CLK	C1	13	I	SWD Clock
I2C_SCL	B1	18	I	I <sup>2</sup> C Slave Clock signal
I2C_SDA	B2	19	I/O	I <sup>2</sup> C Slave Data signal
I2C_INT	A2	20	0	I <sup>2</sup> C INT
XRES	B6	30	Ι	Active Low Reset
VCCD	A7	31	POWER	Connect 1-µF capacitor between VCCD and Ground
VDDD	C7	32	POWER	VCONN Supply
VDDA	C7	33	POWER	
VSSA	B7	34	GND	Ground
VSS	-	9	GND	Ground
CC_VREF	C5	36	I	Data reference signal for CC lines
ADC_BYPASS	E7	40	Ι	No Connect
TX_U	B3	26	0	Signals for internal use only. The TX_U output signal
TX_M	B5	29	Ι	should be connected to the TX_M signal
TX_REF_IN	D3	3	Ι	Reference signal for internal use. Connect to TX_REF output via a 2.4K 1% resistor
TX_GND	A3	25	Ι	Connect to GND via 2K 1% resistor
TX_REF_OUT	D4	39	0	Reference signal generated by connecting internal current source to two 1K external resistors
RA_DISCONNECT	E4	4	0	Optional control signal to remove RA after assertion of VCONN 0: RA disconnected 1: RA connected
CC1_LPREF	A5	23	I	Reference signal for internal use. Connect to the output of resistor divider from VDDD.
VCONN_DET	E5	5	0	Detects presence of VCONN before responding to CC communication
BYPASS	D5	-	I	Bypass capacitor for internal analog circuits
DITAGO	-	37	I	Bypass capacitor for internal analog circuits
CC1_LPRX	C3	22	I	Configuration Channel 1 RX signal for Low Power States
VBUS_DET	B4	28	I	Detects presence of VBUS before enabling Billboard device



Functional Pin Name	CYPD1120-35FNXIT	CYPD1120-40LQXI	Туре	Description
BILLBOARD CTRL	D6	-	0	Enables Billboard Device
DIEEDO/IND_OTHE	_	1	Ũ	
DP_AUX_CTRL	E1	10	0	Closes AUX_P/N switch after successful Alternate Mode entry
AUX_CH_P_SENSE	E2	8	I	Senses presence of DisplayPort on UFP_D
AUX_CH_N_SENSE	E3	7	I	Senses presence of DisplayPort on DFP_D
HOTPLUG_DET	E6	6	I/O	HotPlug Detection/Driver for DisplayPort Alternate Mode
GPIO_0	A1	21	I/O	GPIO
GPIO_1	A6	27	I/O	GPIO
GPIO_2	C2	14	I/O	GPIO
GPIO_3	D2	11	I/O	GPIO
GPIO_4	C6	-	I/O	GPIO
0110_4	-	2	1/0	
GPIO_5	A4	24	I/O	GPIO
GPIO_6	-	15	I/O	GPIO
GPIO_7	-	16	I/O	GPIO
GPIO_8	-	17	I/O	GPIO

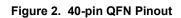
# Table 1. Pin Definition for 40-Pin QFN and 35-Ball WLCSP (continued)

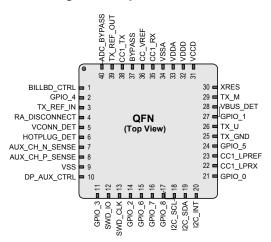
\_\_\_\_\_



# CYPRESS EMBEDDED IN TOMORROW"

# **Pinouts**





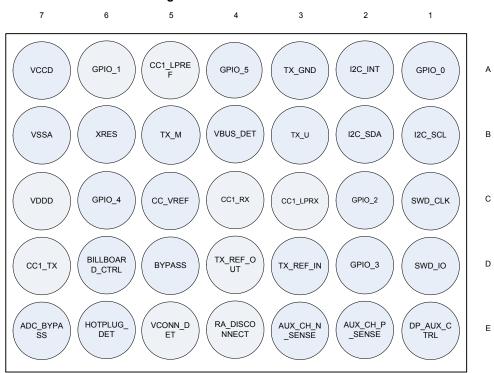


Figure 3. 35-Ball WLCSP Pinout

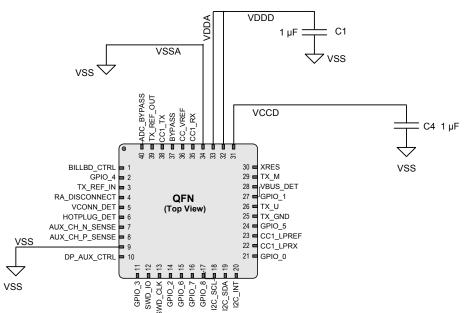


The following power system diagram shows the minimum set of power supply pins as implemented for the CCG1. The system has one regulator in Active mode for the digital circuitry. There is no analog regulator; the analog circuits run directly from the VDDA input. There is a separate regulator for the Deep Sleep mode. There is a separate low-noise regulator for the bandgap. The supply voltage range is 1.8 V to 5.5 V with all functions and circuits operating over that range.

The CCG1 is powered by an external power supply that can be anywhere in the range of 1.8 V to 5.5 V. This range is also designed for battery-powered operation.For example, the chip can be powered from a battery system that starts at 3.5 V and works down to 1.8 V. In this mode, the internal regulator of the CCG1 supplies the internal logic and the VCCD output of the CCG1 must be bypassed to ground via an external capacitor (in the range of 1  $\mu$ F to 1.6  $\mu$ F; X5R ceramic or better). No voltage source should be applied to this pin.

VDDA and VDDD must be shorted together; the grounds, VSSA and VSS must also be shorted together. Bypass capacitors must be used from VDDD to ground. The typical practice for systems in this frequency range is to use a capacitor in the 1- $\mu$ F range in parallel with a smaller capacitor (0.1  $\mu$ F, for example). Note that these are simply rules of thumb and that, for critical applications, the PCB layout, lead inductance, and the bypass capacitor parasitic should be simulated to design and obtain optimal bypassing.

Examples of bypass schemes follow.



#### Figure 4. 40-pin QFN Example



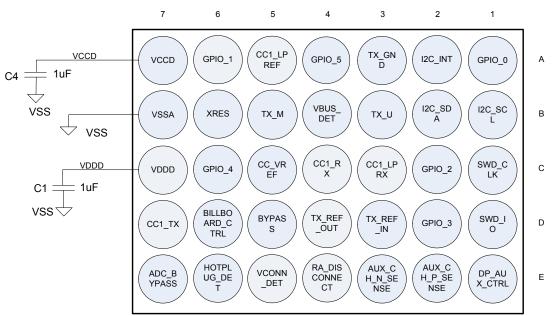


Figure 5. 35-ball WLCSP Example



# **Electrical Specifications**

### Absolute Maximum Ratings

# Table 2. Absolute Maximum Ratings<sup>[6]</sup>

Spec ID#	Parameter	Description	Min	Тур	Мах	Units	Details/ Conditions
SID1	V <sub>DDD_ABS</sub>	Digital supply relative to V <sub>SSD</sub>	-0.5	-	6.0	V	Absolute max
SID2	V <sub>CCD_ABS</sub>	Direct digital core voltage input relative to V <sub>SSD</sub>	-0.5	-	1.95	V	Absolute max
SID3	V <sub>GPIO_ABS</sub>	GPIO voltage	-0.5	-	V <sub>DDD</sub> +0.5	V	Absolute max
SID4	I <sub>GPIO_ABS</sub>	Maximum current per GPIO	-25.0	-	25.0	mA	Absolute max
SID5	I <sub>GPIO_injection</sub>	GPIO injection current, Max for V <sub>IH</sub> > V <sub>DDD</sub> , and Min for V <sub>IL</sub> < V <sub>SS</sub>	-0.50	_	0.5	mA	Absolute max, current injected per pin
BID44	ESD_HBM	Electrostatic discharge human body model	2200	_	-	V	-
BID45	ESD_CDM	Electrostatic discharge charged device model	500	_	-	V	-
BID46	LU	Pin current for latch-up	-200	_	200	mA	-

### **Device Level Specifications**

All specifications are valid for –40 °C  $\leq$  T<sub>A</sub>  $\leq$  85 °C and T<sub>J</sub>  $\leq$  100 °C for 35-CSP and 40-QFN package options. Specifications are valid for 1.8 V to 5.5 V, except where noted.

#### Table 3. DC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID53	V <sub>DDD</sub>	Power supply input voltage	1.8	-	5.5	V	With regulator enabled
SID54	V <sub>CCD</sub>	Output voltage (for core logic)	-	1.8	-	V	-
SID55	C <sub>EFC</sub>	External regulator voltage bypass	1.0	1.3	1.6	μF	X5R ceramic or better
SID56	C <sub>EXC</sub>	Power supply decoupling capacitor	-	1.0	-	μF	X5R ceramic or better
Active Mo	de, V <sub>DDD</sub> = 1	.8 to 5.5 V. Typical values measured at	V <sub>DD</sub> = 3	.3 V.			
SID19	I <sub>DD14</sub>	Execute from flash; CPU at 48 MHz	-	12.8	-	mA	T = 25 °C
SID20	I <sub>DD15</sub>	Execute from flash; CPU at 48 MHz	-	-	13.8	mA	-
Sleep Mo	de, V <sub>DDD</sub> = 1.8	8 to 5.5 V					
SID25A	I <sub>DD20A</sub>	I <sup>2</sup> C wakeup and comparators on	-	1.7	2.2	mA	-
Deep Slee	p Mode, V <sub>DD</sub>	<sub>D</sub> = 1.8 to 3.6 V (Regulator on)					
SID31	I <sub>DD26</sub>	I <sup>2</sup> C wakeup on	-	1.3	-	μA	T = 25 °C, 3.6 V
SID32	I <sub>DD27</sub>	I <sup>2</sup> C wakeup on	-	-	50.0	μA	T = 85 °C
Deep Slee	ep Mode, V <sub>DD</sub>	<sub>D</sub> = 3.6 to 5.5 V					
SID34	I <sub>DD29</sub>	I <sup>2</sup> C wakeup	-	15.0	-	μA	T = 25 °C, 5.5 V
XRES Cui	rent						
SID307	I <sub>DD_XR</sub>	Supply current while XRES asserted	-	2.0	5.0	mA	-

Note

<sup>6.</sup> Usage above the absolute maximum conditions listed in Table 2 may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods of time may affect device reliability. The maximum storage temperature is 150 °C in compliance with JEDEC Standard JESD22-A103, High Temperature Storage Life. When used below absolute maximum conditions but above normal operating conditions, the device may not operate to specification.



### Table 4. AC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID48	F <sub>CPU</sub>	CPU frequency	DC	-	48.0	MHz	$1.8 \le V_{DD} \le 5.5$
SID49	T <sub>SLEEP</sub>	Wakeup from sleep mode	-	0	_	μs	Guaranteed by characterization
SID50	T <sub>DEEPSLEEP</sub>	Wakeup from Deep Sleep mode	_	_	25.0	μs	24-MHz IMO. Guaranteed by characterization
SID52	T <sub>RESETWIDTH</sub>	External reset pulse width	1.0	-	Ι	μs	Guaranteed by characterization

I/O

# Table 5. I/O DC Specifications

Spec ID#	Parameter	Description	Min	Тур	Мах	Units	Details/ Conditions
SID57	V <sub>IH</sub> <sup>[7]</sup>	Input voltage high threshold	0.7 × V <sub>DDD</sub>	_	_	V	CMOS Input
SID58	V <sub>IL</sub>	Input voltage low threshold	-	_	0.3 × V <sub>DDD</sub>	V	CMOS Input
SID241	V <sub>IH</sub> <sup>[7]</sup>	LVTTL input, V <sub>DDD</sub> < 2.7 V	0.7× V <sub>DDD</sub>	_	_	V	_
SID242	V <sub>IL</sub>	LVTTL input, V <sub>DDD</sub> < 2.7 V	_	-	0.3 × V <sub>DDD</sub>	V	_
SID243	V <sub>IH</sub> <sup>[7]</sup>	LVTTL input, $V_{DDD} \ge 2.7 \text{ V}$	2.0	-	-	V	_
SID244	V <sub>IL</sub>	LVTTL input, $V_{DDD} \ge 2.7 V$	-	-	0.8	V	_
SID59	V <sub>OH</sub>	Output voltage high level	V <sub>DDD</sub> -0.6	-	-	V	I <sub>OH</sub> = 4 mA at 3-V V <sub>DDD</sub>
SID60	V <sub>OH</sub>	Output voltage high level	V <sub>DDD</sub> -0.5	-	-	V	I <sub>OH</sub> = 1 mA at 1.8-V V <sub>DDD</sub>
SID61	V <sub>OL</sub>	Output voltage low level	-	—	0.6	V	I <sub>OL</sub> = 4 mA at 1.8-V V <sub>DDD</sub>
SID62	V <sub>OL</sub>	Output voltage low level	-	-	0.6	V	I <sub>OL</sub> = 8 mA at 3-V V <sub>DDD</sub>
SID62A	V <sub>OL</sub>	Output voltage low level	-	-	0.4	V	I <sub>OL</sub> = 3 mA at 3-V V <sub>DDD</sub>
SID63	R <sub>PULLUP</sub>	Pull-up resistor	3.5	5.6	8.5	kΩ	-
SID64	R <sub>PULLDOWN</sub>	Pull-down resistor	3.5	5.6	8.5	kΩ	-
SID65	I <sub>IL</sub>	Input leakage current (absolute value)	-	-	2.0	nA	25 °C, V <sub>DDD</sub> = 3.0 V
SID65A	I <sub>IL_CTBM</sub>	Input leakage current (absolute value) for analog pins	-	-	4.0	nA	-
SID66	C <sub>IN</sub>	Input capacitance	-	—	7.0	pF	_
SID67	V <sub>HYSTTL</sub>	Input hysteresis LVTTL	15.0	40.0	-	mV	$V_{DDD} \ge 2.7$ V. Guaranteed by characterization
SID68	V <sub>HYSCMOS</sub>	Input hysteresis CMOS	200.0	-	-	mV	$V_{DDD} \ge 4.5 \text{ V.}$ Guaranteed by characterization
SID69	I <sub>DIODE</sub>	Current through protection diode to $V_{DD}/V_{SS}$	-	_	100.0	μA	Guaranteed by characterization
SID69A	I <sub>TOT_GPIO</sub>	Maximum Total Source or Sink Chip Current	_	_	200.0	mA	Guaranteed by characterization



# Table 6. I/O AC Specifications

(Guaranteed by Characterization)

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID70	T <sub>RISEF</sub>	Rise time	2.0	-	12.0	ns	3.3-V $V_{DDD}$ , Cload = 25 pF
SID71	T <sub>FALLF</sub>	Fall time	2.0	_	12.0	ns	3.3-V V <sub>DDD</sub> , Cload = 25 pF

XRES

#### Table 7. XRES DC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID77	V <sub>IH</sub>	Input voltage high threshold	0.7 × V <sub>DDD</sub>	_	_	V	CMOS input
SID78	V <sub>IL</sub>	Input voltage low threshold	-	-	0.3 × V <sub>DDD</sub>	V	CMOS input
SID79	R <sub>PULLUP</sub>	Pull-up resistor	3.5	5.6	8.5	kΩ	-
SID80	C <sub>IN</sub>	Input capacitance	-	3.0	-	pF	-
SID81	V <sub>HYSXRES</sub>	Input voltage hysteresis	-	100.0	-	mV	Guaranteed by characterization
SID82	I <sub>DIODE</sub>	Current through protection diode to $V_{DDD}/V_{SS}$	_	_	100.0	μA	Guaranteed by characterization

# **Digital Peripherals**

The following specifications apply to the Timer/Counter/PWM peripherals in the Timer mode.

# Pulse Width Modulation (PWM) for VSEL and CUR\_LIM Pins

# Table 8. PWM AC Specifications

(Guaranteed by Characterization)

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID140	T <sub>PWMFREQ</sub>	Operating frequency	-	-	48.0	MHz	_
SID141	T <sub>PWMPWINT</sub>	Pulse width (internal)	42.0	-	-	ns	_
SID142	T <sub>PWMEXT</sub>	Pulse width (external)	42.0	-	-	ns	_
SID143	T <sub>PWMKILLINT</sub>	Kill pulse width (internal)	42.0	_	-	ns	-
SID144	T <sub>PWMKILLEXT</sub>	Kill pulse width (external)	42.0	-	-	ns	_
SID145	T <sub>PWMEINT</sub>	Enable pulse width (internal)	42.0	-	-	ns	-
SID146	T <sub>PWMENEXT</sub>	Enable pulse width (external)	42.0	-	-	ns	-
SID147	T <sub>PWMRESWINT</sub>	Reset pulse width (internal)	42.0	-	-	ns	_
SID148	<b>T</b> <sub>PWMRESWEXT</sub>	Reset pulse width (external)	42.0	-	-	ns	-

l<sup>2</sup>C

# Table 9. Fixed I<sup>2</sup>C DC Specifications

(Guaranteed by Characterization)

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID149	I <sub>I2C1</sub>	Block current consumption at 100 kHz	-	-	10.5	μA	_
SID150	I <sub>I2C2</sub>	Block current consumption at 400 kHz	_	-	135.0	μA	_
SID151	I <sub>I2C3</sub>	Block current consumption at 1 Mbps	-	-	310.0	μA	_
SID152	I <sub>I2C4</sub>	I <sup>2</sup> C enabled in Deep Sleep mode	-	-	1.4	μA	_



# Table 10. Fixed I<sup>2</sup>C AC Specifications

(Guaranteed by Characterization)

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID153	F <sub>I2C1</sub>	Bit rate	Ι	-	1.0	Mbps	_

### Memory

#### Table 11. Flash DC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID173	V <sub>PE</sub>	Erase and program voltage	1.8	-	5.5	V	-

#### Table 12. Flash AC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID174	T <sub>ROWWRITE</sub> <sup>[8]</sup>	Row (block) write time (erase and program)	-	-	20.0	ms	Row (block) = 128 bytes
SID175	T <sub>ROWERASE</sub> <sup>[8]</sup>	Row erase time	-	-	13.0	ms	-
SID176	T <sub>ROWPROGRAM</sub> <sup>[8]</sup>	Row program time after erase	-	-	7.0	ms	-
SID178	T <sub>BULKERASE</sub> <sup>[8]</sup>	Bulk erase time (32 KB)	-	-	35	ms	-
SID180	T <sub>DEVPROG</sub> <sup>[8]</sup>	Total device program time	-	-	7.0	second s	Guaranteed by characterization
SID181	F <sub>END</sub>	Flash endurance	100 K	-	-	cycles	Guaranteed by characterization
SID182	F <sub>RET</sub> <sup>[9]</sup>	Flash retention. $T_A \le 55 \text{ °C}$ , 100 K P/E cycles	20	_	_	years	Guaranteed by characterization
SID182A	-	Flash retention. $T_A \le 85 \text{ °C}$ , 10 K P/E cycles	10	_	_	years	Guaranteed by characterization
SID182B	-	Flash retention. 85 °C < T <sub>A</sub> ≤ 105 °C, 10K P/E cycles	3	_	_	years	Guaranteed by characterization

#### System Resources

Power-on-Reset (POR) with Brown Out

#### Table 13. Imprecise Power On Reset (PRES)

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID185	V <sub>RISEIPOR</sub>	Rising trip voltage	0.80	-	1.45	V	Guaranteed by characterization
SID186	V <sub>FALLIPOR</sub>	Falling trip voltage	0.75	-	1.40	V	Guaranteed by characterization
SID187	VIPORHYST	Hysteresis	15.0	-	200.0	mV	Guaranteed by characterization

#### Table 14. Precise Power On Reset (POR)

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID190	V <sub>FALLPPOR</sub>	BOD trip voltage in active and sleep modes	1.64	-	-	V	Guaranteed by characterization
SID192	V <sub>FALLDPSLP</sub>	BOD trip voltage in Deep Sleep	1.40	-	_	V	Guaranteed by characterization

Note

 It can take as much as 20 milliseconds to write to flash. During this time the device should not be Reset, or flash operations will be interrupted and cannot be relied on to have completed. Reset sources include the XRES pin, software resets, CPU lockup states and privilege violations, improper power supply levels, and watchdogs. Make certain that these are not inadvertently activated.

Cypress provides a retention calculator to calculate the retention lifetime based on customers' individual temperature profiles for operation over the -40 °C to +105 °C ambient temperature range. Contact customercare@cypress.com.



#### SWD Interface

### Table 15. SWD Interface Specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID213	F_SWDCLK1	$3.3 \text{ V} \le \text{V}_{\text{DDD}} \le 5.5 \text{ V}$	_	-	14.0	MHz	SWDCLK ≤ 1/3 CPU clock frequency
SID214	F_SWDCLK2	$1.8 \text{ V} \leq \text{V}_{\text{DDD}} \leq 3.3 \text{ V}$	-	_	7.0	MHz	SWDCLK ≤ 1/3 CPU clock frequency
SID215	T_SWDI_SETUP	T = 1/f SWDCLK	0.25*T	-	_	ns	Guaranteed by characterization
SID216	T_SWDI_HOLD	T = 1/f SWDCLK	0.25*T	-	_	ns	Guaranteed by characterization
SID217	T_SWDO_VALID	T = 1/f SWDCLK	-	-	0.5*T	ns	Guaranteed by characterization
SID217A	T_SWDO_HOLD	T = 1/f SWDCLK	1	-	-	ns	Guaranteed by characterization

#### Internal Main Oscillator

# Table 16. IMO DC Specifications

(Guaranteed by Design)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID218	I <sub>IMO1</sub>	IMO operating current at 48 MHz	_	-	1000.0	μA	-

# Table 17. IMO AC Specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID223	F <sub>IMOTOL1</sub>	Frequency variation	-	-	±2.0	%	With API-called calibration
SID226	T <sub>STARTIMO</sub>	IMO startup time	-	-	12.0	μs	-
SID229	T <sub>JITRMSIMO3</sub>	RMS Jitter at 48 MHz	-	139.0	-	ps	-

Internal Low-Speed Oscillator

#### Table 18. ILO DC Specifications

(Guaranteed by Design)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID231	I <sub>ILO1</sub>	ILO operating current at 32 kHz	-	0.30	1.05	μA	Guaranteed by characterization
SID233	I <sub>ILOLEAK</sub>	ILO leakage current	-	2.0	15.0	nA	Guaranteed by design

#### Table 19. ILO AC Specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID234	T <sub>STARTILO1</sub>	ILO startup time	-	-	2.0	ms	Guaranteed by characterization
SID236	T <sub>ILODUTY</sub>	ILO duty cycle	40.0	50.0	60.0	%	Guaranteed by characterization
SID237	F <sub>ILOTRIM1</sub>	32-kHz trimmed frequency	15.0	32.0	50.0	kHz	±60% with trim





# **Applications in Detail**

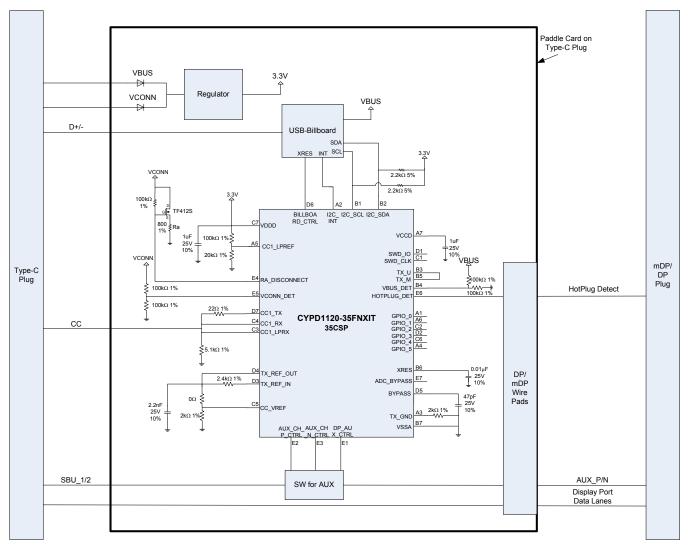


Figure 6. Type-C to DisplayPort/Mini-DisplayPort Application Using 35-CSP Package



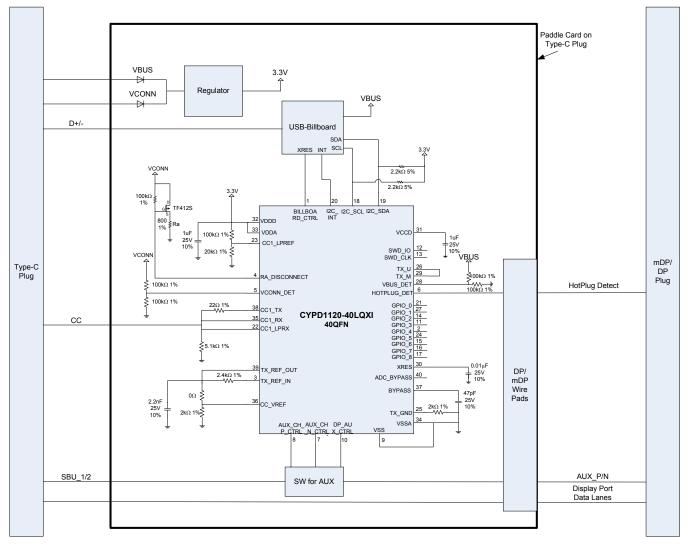


Figure 7. Type-C to DisplayPort/mini-DisplayPort Application Using 40-QFN Package





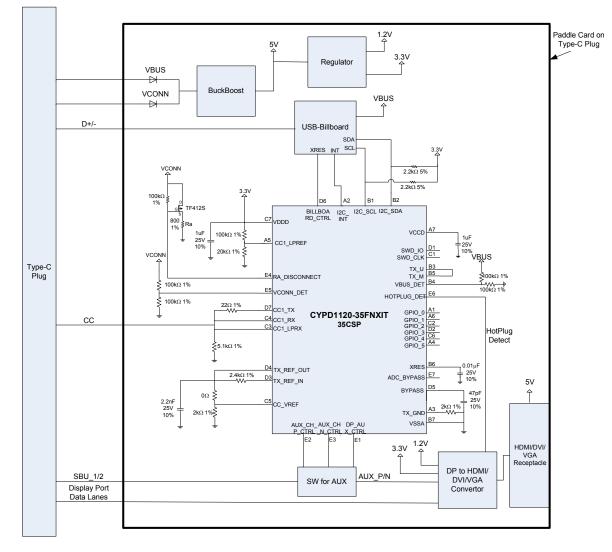


Figure 8. Type-C to HDMI Application Using 35-CSP Package





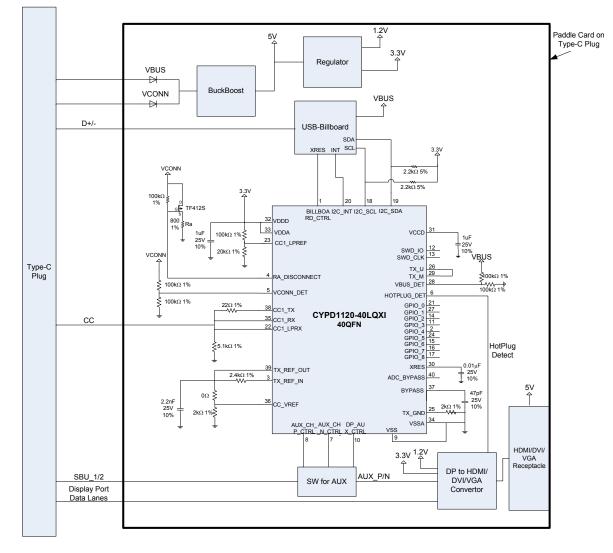


Figure 9. Type-C to HDMI Application Using 40-QFN Package



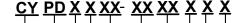
# **Ordering Information**

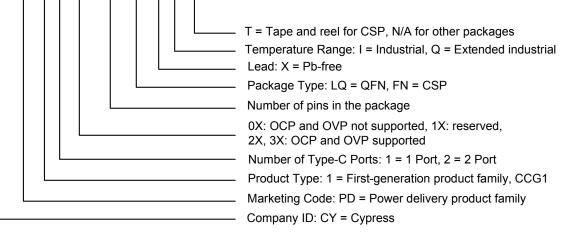
The CCG1 part numbers and features are listed in the following table.

### Table 20. CCG1 Ordering Information

Part Number <sup>[10]</sup>	Application	Type-C Ports <sup>[11]</sup>	Termination Resistor <sup>[12]</sup>	<b>Role</b> <sup>[13]</sup>	Package	Si ID
CYPD1120-35FNXIT	Type-C to DP, Type-C to HDMI	1	R <sub>d</sub> <sup>[14]</sup>	UFP <sup>[17]</sup>	35-WLCSP <sup>[15]</sup>	0492
CYPD1120-40LQXI	Type-C to DP, Type-C to HDMI	1	R <sub>d</sub> <sup>[14]</sup>	UFP <sup>[17]</sup>	40-QFN <sup>[16]</sup>	0488
CYPD1120-40LQXIT	Type-C to DP, Type-C to HDMI	1	R <sub>d</sub> <sup>[14]</sup>	UFP <sup>[17]</sup>	40-QFN <sup>[16]</sup>	0488

# **Ordering Code Definitions**





- Notes 10. All part numbers support: Input voltage range from 1.8 to 5.5 V. Industrial parts support -40 °C to +85 °C, Extended Industrial parts support -40 °C to 105 °C. 11. Number of USB Type-C Ports Supported .
- 12. Default V<sub>CONN</sub> Termination.
- 13. PD Role.
   14. Termination resistor denoting an upstream facing port.
   15. 35-WLCSP#1 pinout.
- 16. 40-QFN#3 pinout.
- 17. Upstream Facing Port.



# Packaging

# Table 21. Package Characteristics

Parameter	Description	Conditions	Min	Тур	Мах	Units
T <sub>A</sub> (40-QFN, 35-CSP)	Operating ambient temperature	-	-40	25.00	85	°C
T <sub>J</sub> (40-QFN, 35-CSP)	Operating junction temperature	-	-40	-	100	°C
T <sub>JA</sub>	Package θJA (40-pin QFN)	-	-	15.34	-	°C/Watt
T <sub>JA</sub>	Package θJA (35-CSP)	-	-	28.00	-	°C/Watt
T <sub>JC</sub>	Package θJC (40-pin QFN)	-	-	02.50	1	°C/Watt

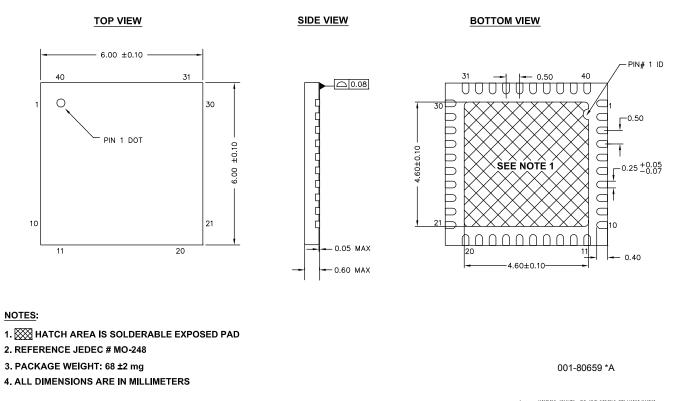
#### Table 22. Solder Reflow Peak Temperature

Package	Maximum Peak Temperature	Maximum Time at Peak Temperature		
40-pin QFN	260 °C	30 seconds		
35-ball WLCSP	260 °C	30 seconds		

### Table 23. Package Moisture Sensitivity Level (MSL), IPC/JEDEC J-STD-2

Package	MSL
40-pin QFN	MSL 3
35-ball WLCSP	MSL 1

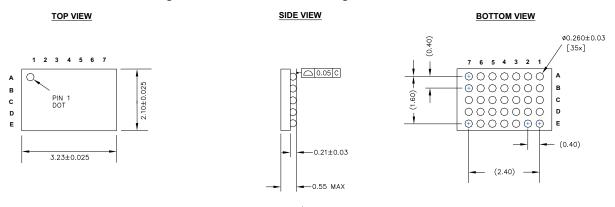




#### Figure 10. 40-pin QFN Package Outline, 001-80659

The center pad on the QFN package should be connected to ground (VSS) for best mechanical, thermal, and electrical performance. If not connected to ground, it should be electrically floating and not connected to any other signal.

#### Figure 11. 35-Ball WLCSP Package Outline, 001-93741



#### NOTES:

1. REFERENCE JEDEC PUBLICATION 95, DESIGN GUIDE 4.18

2. ALL DIMENSIONS ARE IN MILLIMETERS

001-93741 \*\*



# Acronyms

## Table 24. Acronyms Used in this Document

Acronym	Description
ADC	analog-to-digital converter
API	application programming interface
ARM®	advanced RISC machine, a CPU architecture
CC	Configuration Channel
CPU	central processing unit
CRC	cyclic redundancy check, an error-checking protocol
CS	Current Sense
DFP	Downstream Facing Port
DIO	digital input/output, GPIO with only digital capabilities, no analog. See GPIO.
DP	DisplayPort
EEPROM	electrically erasable programmable read-only memory
EMI	electromagnetic interference
ESD	electrostatic discharge
FPB	flash patch and breakpoint
FS	full-speed
GPIO	general-purpose input/output, applies to a PSoC pin
IC	integrated circuit
IDE	integrated development environment
I <sup>2</sup> C, or IIC	Inter-Integrated Circuit, a communications protocol
ILO	internal low-speed oscillator, see also IMO
IMO	internal main oscillator, see also ILO
I/O	input/output, see also GPIO, DIO, SIO, USBIO
LVD	low-voltage detect
LVTTL	low-voltage transistor-transistor logic
MCU	microcontroller unit
NC	no connect
NMI	nonmaskable interrupt
NVIC	nested vectored interrupt controller

#### Table 24. Acronyms Used in this Document (continued)

Acronym	Description
opamp	operational amplifier
OCP	Overcurrent protection
OVP	Overvoltage protection
РСВ	printed circuit board
PGA	programmable gain amplifier
PHY	physical layer
POR	power-on reset
PRES	precise power-on reset
PSoC <sup>®</sup>	Programmable System-on-Chip™
PWM	pulse-width modulator
RAM	random-access memory
RISC	reduced-instruction-set computing
RMS	root-mean-square
RTC	real-time clock
RX	receive
SAR	successive approximation register
SCL	I <sup>2</sup> C serial clock
SDA	I <sup>2</sup> C serial data
S/H	sample and hold
SPI	Serial Peripheral Interface, a communications protocol
SRAM	static random access memory
SWD	serial wire debug, a test protocol
ТХ	transmit
UART	Universal Asynchronous Transmitter Receiver, a communications protocol
UFP	Upstream Facing Port
USB	Universal Serial Bus
USBIO	USB input/output, PSoC pins used to connect to a USB port
VESA	Video Electronics Standards Association
XRES	external reset I/O pin



# **Document Conventions**

# Units of Measure

# Table 25. Units of Measure

Symbol	Unit of Measure
°C	degrees Celsius
Hz	hertz
KB	1024 bytes
kHz	kilohertz
kΩ	kilo ohm
Mbps	megabits per second
MHz	megahertz
MΩ	mega-ohm
Msps	megasamples per second
μA	microampere
μF	microfarad
μs	microsecond
μV	microvolt
μW	microwatt
mA	milliampere
ms	millisecond
mV	millivolt
nA	nanoampere
ns	nanosecond
Ω	ohm
pF	picofarad
ppm	parts per million
ps	picosecond
S	second
sps	samples per second
V	volt



# **Revision History**

Description Title: CYPD1120, USB Power Delivery Alternate Mode Controller on Type-C Document Number: 001-96786				
Revision	ECN	Orig. of Change	Submission Date	Description of Change
**	4686071	VGT	05/13/2015	New datasheet
*A	4829889	VGT	07/20/2015	Added CYPD1120-40LQXIT in Ordering Information.
*В	5104916	VGT	02/05/2016	Updated Ordering Information.
*C	5705375	VGT		Updated Sales, Solutions, and Legal Information. Updated Copyright and Disclaimer. Updated template.



# Sales, Solutions, and Legal Information

#### Worldwide Sales and Design Support

Cypress maintains a worldwide network of offices, solution centers, manufacturer's representatives, and distributors. To find the office closest to you, visit us at Cypress Locations.

#### Products

ARM <sup>®</sup> Cortex <sup>®</sup> Microcontrollers	cypress.com/arm
Automotive	cypress.com/automotive
Clocks & Buffers	cypress.com/clocks
Interface	cypress.com/interface
Internet of Things	cypress.com/iot
Memory	cypress.com/memory
Microcontrollers	cypress.com/mcu
PSoC	cypress.com/psoc
Power Management ICs	cypress.com/pmic
Touch Sensing	cypress.com/touch
USB Controllers	cypress.com/usb
Wireless Connectivity	cypress.com/wireless

# **PSoC<sup>®</sup> Solutions**

PSoC 1 | PSoC 3 | PSoC 4 | PSoC 5LP

#### **Cypress Developer Community**

Forums | WICED IOT Forums | Projects | Video | Blogs | Training | Components

#### **Technical Support**

cypress.com/support

Notice regarding compliance with Universal Serial Bus specification. Cypress offers firmware and hardware solutions that are certified to comply with the Universal Serial Bus specification, USB Type-C<sup>™</sup> Cable and Connector Specification, and other specifications of USB Implementers Forum, Inc (USB-IF). You may use Cypress or third party software tools, including sample code, to modify the firmware for Cypress USB products. Modification of such firmware could cause the firmware/hardware combination to no longer comply with the relevant USB-IF specification. You are solely responsible ensuring the compliance of any modifications you make, and you must follow the compliance requirements of USB-IF before using any USB-IF trademarks or logos in connection with any modifications you make. In addition, if Cypress modifies firmware based on your specifications, then you are responsible for ensuring compliance with any desired standard or specifications as if you had made the modification. CYPRESS IS NOT RESPONSIBLE IN THE EVENT THAT YOU MODIFY OR HAVE MODIFIED A CERTIFIED CYPRESS PRODUCT AND SUCH MODIFIED PRODUCT NO LONGER COMPLIES WITH THE RELEVANT USB-IF SPECIFICATIONS.

© Cypress Semiconductor Corporation, 2015-2017. This document is the property of Cypress Semiconductor Corporation and its subsidiaries, including Spansion LLC ("Cypress"). This document, including any software or firmware included or referenced in this document ("Software"), is owned by Cypress under the intellectual property laws and treaties of the United States and other countries worldwide. Cypress reserves all rights under such laws and treaties and does not, except as specifically stated in this paragraph, grant any license under its patents, copyrights, trademarks, or other intellectual property rights. If the Software is not accompanied by a license agreement and you do not otherwise have a written agreement with Cypress governing the use of the Software, then Cypress paratry yights and exclusive, nontransferable license (without the right to sublicense) (1) under its copyright rights in the Software provided in source code form, to modify and reproduce the Software solely for use with Cypress hardware products, only internally within your organization, and (b) to distribute the Software in binary code form externally to end users (either directly or indirectly through resellers and distributors), solely for use on Cypress hardware product units, and (2) under those claims of Cypress's patents that are infringed by the Software (as provided by Cypress, unmodified) to make, use, distribute, and import the Software solely for use with Cypress hardware products. Any other use, reproduction, modification, translation, or compilation of the Software is prohibited.

TO THE EXTENT PERMITTED BY APPLICABLE LAW, CYPRESS MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARD TO THIS DOCUMENT OR ANY SOFTWARE OR ACCOMPANYING HARDWARE, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE. To the extent permitted by applicable law, Cypress reserves the right to make changes to this document without further notice. Cypress does not assume any liability arising out of the application or use of any product or circuit described in this document. Any information provided in this document, including any sample design information or programming code, is provided only for reference purposes. It is the responsibility of the user of this document to properly design, program, and test the functionality and safety of any application made of this information and any resulting product. Cypress products are not designed, intended, or authorized for use as critical components in systems designed or intended for the operation of weapons, weapons systems, nuclear installations, life-support devices or systems, other medical devices or systems (including resuscitation equipment and surgical implants), pollution control or hazardous substances management, or other tuses where the failure of the device or system could cause personal injury, death, or property damage ("Unintended Uses"). A critical component is any component of a device or system whose failure to perform can be reasonably expected to cause the failure of the device or system, or to affect its safety or effectiveness. Cypress is not liable, in whole or in part, and you shall and hereby do release Cypress from any claim, damage, or other liability arising from or related to any Unintended Uses of Cypress products.

Cypress, the Cypress logo, Spansion, the Spansion logo, and combinations thereof, WICED, PSoC, CapSense, EZ-USB, F-RAM, and Traveo are trademarks or registered trademarks of Cypress in the United States and other countries. For a more complete list of Cypress trademarks, visit cypress.com. Other names and brands may be claimed as property of their respective owners.